

Product Specification PE4239

SPDT UltraCMOS™ RF Switch

Features

- Single-pin or complementary CMOS logic control inputs
- +3.0-volt power supply needed for single-pin control mode
- Low insertion loss: 0.7 dB at 1.0 GHz. 0.9 dB at 2.0 GHz
- Isolation of 32 dB at 1.0 GHz, 23 dB at 2.0 GHz
- Typical input 1 dB compression point of +27 dBm
- Ultra-small SC-70 package

Product Description

The PE4239 UltraCMOS™ RF Switch is designed to cover a broad range of applications from DC through 3.0 GHz. This reflective switch integrates on-board CMOS control logic with a low voltage CMOS-compatible control interface, and can be controlled using either single-pin or complementary control inputs. Using a nominal +3-volt power supply voltage, a typical input 1 dB compression point of +27 dBm can be achieved.

The PE4239 UltraCMOS™ RF Switch is manufactured in Peregrine's patented Ultra Thin Silicon (UTSi®) CMOS process, offering the performance of GaAs with the economy and integration of conventional CMOS.

Figure 1. Functional Diagram

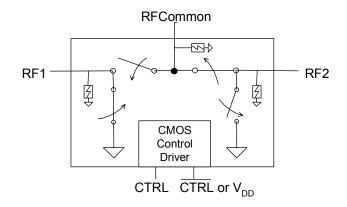


Figure 2. Package Type SC-70 6-lead SC-70



Table 1. Electrical Specifications @ +25 °C, V_{DD} = 3 V (Z_{S} = Z_{L} = 50 Ω)

Parameter	Conditions	Minimum	Typical	Maximum	Units
Operation Frequency ¹		DC		3000	MHz
	1000 MHz		0.7	0.85	dB
Insertion Loss	2000 MHz		0.9	1.05	dB
loclation	1000 MHz	30	32		dB
Isolation	2000 MHz	21	23		dB
Return Loss	1000 MHz	18	20		dB
	2000 MHz	16	18		dB
'ON' Switching Time	50% CTRL to 0.1 dB of final value, 1 GHz		300		ns
'OFF' Switching Time	50% CTRL to 25 dB isolation, 1 GHz		200		ns
Video Feedthrough ²			15		mV_{pp}
Input 1 dB Compression	2000 MHz	26	27		dBm
Input IP3	2000 MHz, 14 dBm input power	43	45		dBm

Notes: 1. Device linearity will begin to degrade below 10 MHz.

^{2.} The DC transient at the output of any port of the switch when the control voltage is switched from Low to High or High to Low in a 50 Ω test set-up, measured with 1ns risetime pulses and 500 MHz bandwidth.



Figure 3. Pin Configuration (Top View)

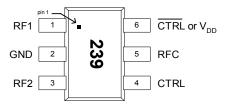


Table 2. Pin Descriptions

Pin No.	Pin Name	Description
1	RF1	RF1 port (Note 1)
2	GND	Ground connection. Traces should be physically short and connected to ground plane for best performance.
3	RF2	RF2 port (Note 1)
4	CTRL	Switch control input, CMOS logic level.
5	RFC	Common RF port for switch (Note 1)
6	CTRL or	This pin supports two interface options:
	V_{DD}	Single-pin control mode. A nominal 3-volt supply connection is required.
		Complementary-pin control mode. A complementary CMOS control signal to CTRL is supplied to this pin. Bypassing on this pin is not required in this mode.

Note 1: All RF pins must be DC blocked with an external series capacitor or held at 0 $\rm V_{DC}$.

Table 3. Absolute Maximum Ratings

Symbol	Parameter/Conditions	Min	Max	Units
V_{DD}	Power supply voltage	-0.3	4.0	V
Vı	Voltage on any input	-0.3	V _{DD} + 0.3	V
T _{ST}	Storage temperature range	-65	150	°C
T _{OP}	Operating temperature range	-40	85	°C
P _{IN}	Input power (50Ω)		30	dBm
V _{ESD}	ESD voltage (Human Body Model)		1500	V

Table 4. DC Electrical Specifications

Parameter	Min	Тур	Max	Units
V _{DD} Power Supply Voltage	2.7	3.0	3.3	V
IDD Power Supply Current		250	500	nA
$(V_{DD} = 3V, V_{CTRL} = 3V)$				
Control Voltage High	$0.7x V_{DD}$			V
Control Voltage Low			0.3x V _{DD}	V

Electrostatic Discharge (ESD) Precautions

When handling this UltraCMOS™ device, observe the same precautions that you would use with other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the specified rating.

Latch-Up Avoidance

Unlike conventional CMOS devices, UltraCMOS™ devices are immune to latch-up.



Table 5. Single-pin Control Logic Truth Table

Control Voltages	Signal Path	
Pin 6 ($\overline{\text{CTRL}}$ or V_{DD}) = V_{DD}	RFC to RF1	
Pin 4 (CTRL) = High	NEG 10 KE I	
Pin 6 (\overline{CTRL} or V_{DD}) = V_{DD}	RFC to RF2	
Pin 4 (CTRL) = Low	KFC 10 KF2	

Table 6. Complementary-pin Control Logic **Truth Table**

Control Voltages	Signal Path	
Pin 6 (CTRL or V_{DD}) = Low Pin 4 (CTRL) = High	RFC to RF1	
Pin 6 ($\overline{\text{CTRL}}$ or V_{DD}) = High Pin 4 ($\overline{\text{CTRL}}$) = Low	RFC to RF2	

Control Logic Input

The PE4239 is a very versatile RF CMOS switch that supports two operating control modes; singlepin control mode and complementary-pin control mode.

Single-pin control mode enables the switch to operate with a single control pin (pin 4) supporting a +3-volt CMOS logic input, and requires a dedicated +3-volt power supply connection on pin 6 (V_{DD}). This mode of operation reduces the number of control lines required and simplifies the switch control interface typically derived from a CMOS µProcessor I/O port.

Complementary-pin control mode allows the switch to operate using complementary control pins CTRL and CTRL (pins 4 & 6), that can be directly driven by +3-volt CMOS logic or a suitable μProcessor I/O port. This enables the PE4239 to be used as a potential alternate source for SPDT RF switch products used in positive control voltage mode and operating within the PE4239 operating limits.



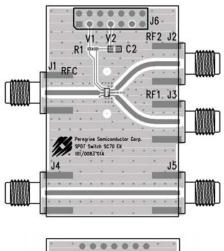
Evaluation Kit

The SPDT Switch Evaluation Kit board was designed to ease customer evaluation of the PE4239 SPDT switch. The RF common port is connected through a 50Ω transmission line to the top left SMA connector, J1. Port 1 and Port 2 are connected through 50Ω transmission lines to the top two SMA connectors on the right side of the board, J3 and J2, respectively. A through transmission line connects SMA connectors J4 and J5. This transmission line can be used to estimate the loss of the PCB over the environmental conditions being evaluated.

The board is constructed of a two metal laver FR4 material with a total thickness of 0.031". The bottom layer provides ground for the RF transmission lines. The transmission lines were designed using a coplanar waveguide with ground plane model using a trace width of 0.0476", trace gaps of 0.030", dielectric thickness of 0.028", metal thickness of 0.0021" and ε_r of 4.4.

J6 provides a means for controlling DC and digital inputs to the device. Starting from the lower left pin, the second pin to the right (J6-3) is connected to the device V1 or CTRL input. The fourth pin to the right (J6-7) is connected to the device V2 or CTRL/V_{DD} input.

Figure 4. Evaluation Board Layout



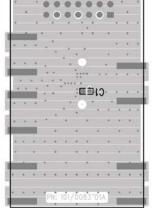
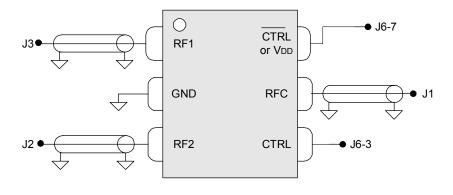


Figure 5. Evaluation Board Schematic







Typical Performance Data @ -40 °C to 85 °C (Unless otherwise noted)

Figure 6. Insertion Loss – RFC to RF1

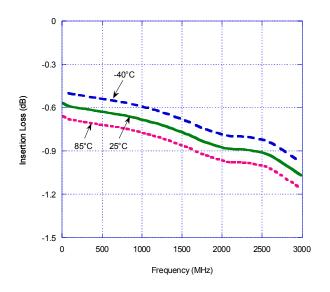


Figure 7. Input 1 dB Compression Point & IIP3 (Typical performance @ 25 °C)

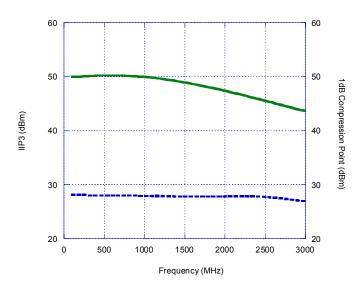


Figure 8. Insertion Loss – RFC to RF2

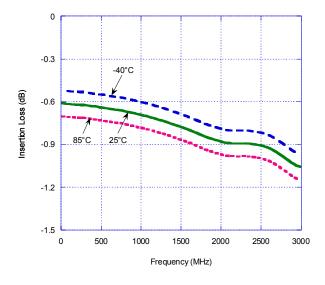
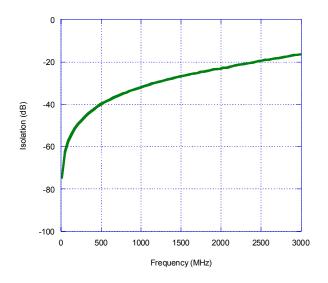


Figure 9. Isolation - RFC to RF1





Typical Performance Data @ -40 °C to 85 °C (Unless otherwise noted)

Figure 10. Isolation – RFC to RF2

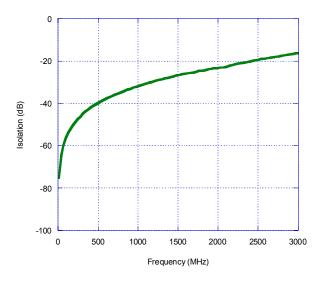


Figure 11. Isolation - RF1 to RF2, RF2 to RF1

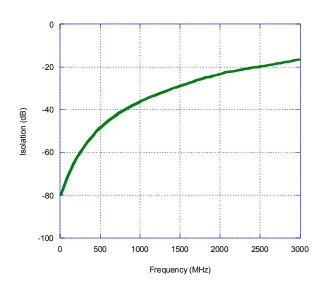


Figure 12. Return Loss – RFC to RF1, RF2

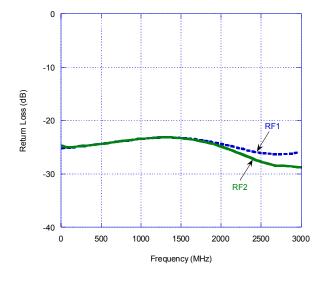


Figure 13. Return Loss - RF1, RF2

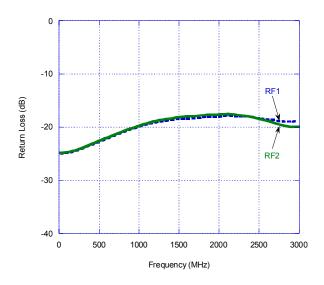
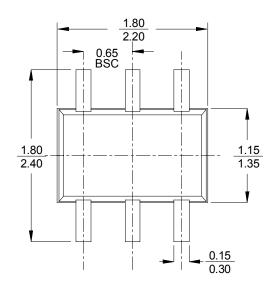
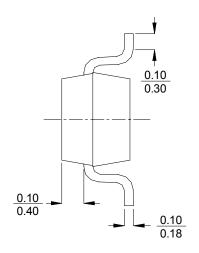


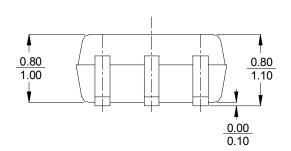


Figure 14. Package Drawing

6-lead SC-70







- 1. ALL DIMENSIONS ARE IN MILLIMETERS
 2. DIMENSIONS ARE INCLUSIVE OF PLATING
- 3. DIMENSIONS ARE EXCLUSIVE OF MOLD FLASH & METAL
- 4. ALL SPECIFICATIONS COMPLY TO EIAJ SC70

Table 7. Ordering Information

Order Code	Part Marking	Description	Package	Shipping Method
4239-01	239	PE4239-06SC70-7680A	6-lead SC-70	7680 units / Canister
4239-02	239	PE4239-06SC70-3000C	6-lead SC-70	3000 units / T&R
4239-00	PE4239-EK	PE4239-06SC70-EK	Evaluation Kit	1 / Box
4239-51	239	PE4239G-06SC70-7680A	Green 6-lead SC-70	7680 units / Canister
4239-52	239	PE4239G-06SC70-3000C	Green 6-lead SC-70	3000 units / T&R



Sales Offices

United States

Peregrine Semiconductor Corp.

9450 Carroll Park Drive San Diego, CA 92121 Tel 1-858-731-9400 Fax 1-858-731-9499

Europe

Peregrine Semiconductor Europe

Bâtiment Maine 13-15 rue des Quatre Vents F- 92380 Garches, France Tel: 011- 33-1-47-41-91-73 Fax: 011-33-1-47-41-91-73

Japan

Peregrine Semiconductor K.K.

5A-5, 5F Imperial Tower 1-1-1 Uchisaiwaicho, Chiyoda-ku Tokyo 100-0011 Japan Tel: 011-81-3-3502-5211

Fax: 011-81-3-3502-5213

China

Peregrine Semiconductor

28G, Times Square, No. 500 Zhangyang Road, Shanghai, 200122, P.R. China Tel: 011-86-21-5836-8276

Fax: 011-86-21-5836-7652

For a list of representatives in your area, please refer to our Web site at: www.psemi.com

Data Sheet Identification

Advance Information

The product is in a formative or design stage. The data sheet contains design target specifications for product development. Specifications and features may change in any manner without notice.

Preliminary Specification

The data sheet contains preliminary data. Additional data may be added at a later date. Peregrine reserves the right to change specifications at any time without notice in order to supply the best possible product.

Product Specification

The data sheet contains final data. In the event Peregrine decides to change the specifications, Peregrine will notify customers of the intended changes by issuing a DCN (Document Change Notice).

The information in this data sheet is believed to be reliable. However, Peregrine assumes no liability for the use of this information. Use shall be entirely at the user's own risk.

No patent rights or licenses to any circuits described in this data sheet are implied or granted to any third party.

Peregrine's products are not designed or intended for use in devices or systems intended for surgical implant, or in other applications intended to support or sustain life, or in any application in which the failure of the Peregrine product could create a situation in which personal injury or death might occur. Peregrine assumes no liability for damages, including consequential or incidental damages, arising out of the use of its products in such applications.

The Peregrine name, logo, and UTSi are registered trademarks and UltraCMOS is a trademark of Peregrine Semiconductor Corp.